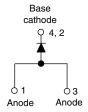


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High Performance Schottky Rectifier, 5.5 A





$J_D N K$	(TO-252AA)
J-FAIL ((IO-232AA)

PRODUCT SUMMARY							
Package	D-PAK (TO-252AA)						
I _{F(AV)}	5.5 A						
V _R	60 V						
V _F at I _F	See Electrical table						
I _{RM}	35 mA at 125 °C						
T _J max.	150 °C						
Diode variation	Single die						
E _{AS}	7 mJ						

FEATURES

- Popular D-PAK outline
- Small foot print, surface mountable



- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

The VS-50WQ06FNPbF surface mount Schottky rectifier has been designed for applications requiring low forward drop and small foot prints on PC board. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS										
SYMBOL	CHARACTERISTICS	VALUES	UNITS							
I _{F(AV)}	Rectangular waveform	5.5	A							
V_{RRM}		60	V							
I _{FSM}	t _p = 5 μs sine	320	Α							
V _F	5 A _{pk} , T _J = 125 °C	0.54	V							
TJ	Range	-40 to +150	°C							

VOLTAGE RATINGS								
PARAMETER	SYMBOL	VS-50WQ06FNPbF	UNITS					
Maximum DC reverse voltage	V_{R}	60	V					
Maximum working peak reverse voltage	V_{RWM}	00	V					

ABSOLUTE MAXIMUM RATINGS								
PARAMETER	SYMBOL	TEST CONDI	VALUES	UNITS				
Maximum average forward current See fig. 5	I _{F(AV)}	50 % duty cycle at T _C = 132 °C	5.5					
Maximum peak one cycle non-repetitive surge current	1	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with	320	Α			
See fig. 7	I _{FSM}	10 ms sine or 6 ms rect. pulse	rated V _{RRM} applied	105				
Non-repetitive avalanche energy	E _{AS}	T _J = 25 °C, I _{AS} = 1.2 A, L = 10 n	7	mJ				
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero Frequency limited by T _J maximo	0.8	А				



ELECTRICAL SPECIFICATIONS									
PARAMETER	SYMBOL	TEST CO	VALUES	UNITS					
		5 A	- T _{.1} = 25 °C	0.57	V				
Maximum forward voltage drop	V _{FM} ⁽¹⁾	10 A	11 = 23 0	0.74					
See fig. 1	V FM (1)	5 A	T _{.1} = 125 °C	0.54					
		10 A	- IJ = 125 C	0.68					
Maximum reverse leakage current	I _{RM} ⁽¹⁾	T _J = 25 °C	- V _R = Rated V _R	3	mA				
See fig. 2		T _J = 125 °C	VR = nateu VR	35					
Threshold voltage	V _{F(TO)}	$T_{ij} = T_{ij}$ maximum		0.35	V				
Forward slope resistance	r _t	IJ = IJ Maximum	25.5	mΩ					
Typical junction capacitance	C _T	V _R = 5 V _{DC} (test signal ran	360	pF					
Typical series inductance	L _S	Measured lead to lead 5 r	5.0	nH					
Maximum voltage rate of change	dV/dt	Rated V _R	10 000	V/µs					

Note

 $^{^{(1)}\,}$ Pulse width < 300 µs, duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS									
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS					
Maximum junction and storage temperature range	T _J ⁽¹⁾ , T _{Stg}		-40 to +150	°C					
Maximum thermal resistance, junction to case	R _{thJC}	DC operation See fig. 4	3.0	°C/W					
Approximate weight			0.3	g					
Approximate weight			0.01	OZ.					
Marking device		Case style D-PAK (similar to TO-252AA)	50WC	06FN					

Note

(1)
$$\frac{dP_{tot}}{dT_1} < \frac{1}{R_{th,1A}}$$
 thermal runaway condition for a diode on its own heatsink

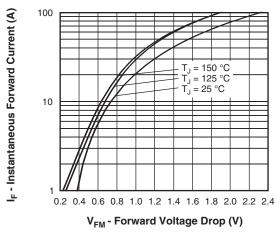


Fig. 1 - Maximum Forward Voltage Drop Characteristics

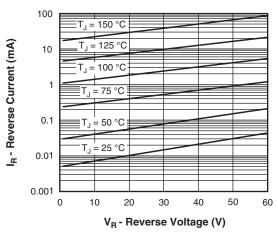


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

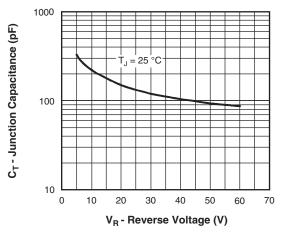


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

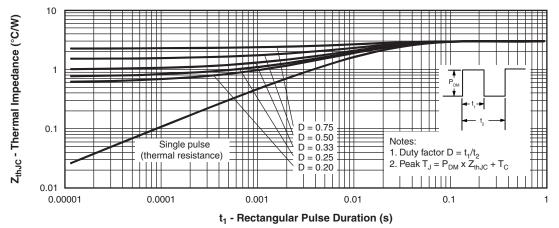


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics





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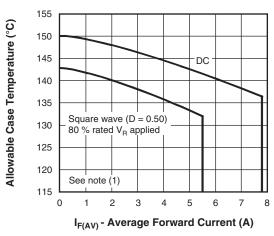


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

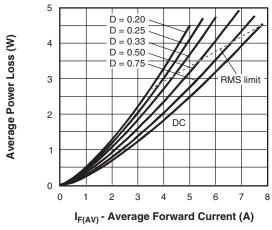


Fig. 6 - Forward Power Loss Characteristics

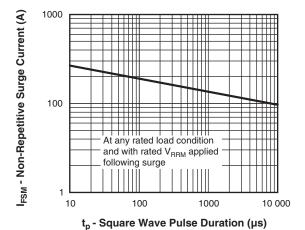


Fig. 7 - Maximum Non-Repetitive Surge Current

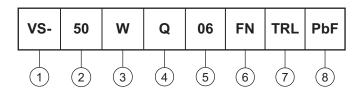
Note

 $^{(1)}$ Formula used: T_C = T_J - (Pd + Pd_{REV}) x R_{thJC}; Pd = forward power loss = I_{F(AV)} x V_{FM} at (I_{F(AV)}/D) (see fig. 6); Pd_{REV} = inverse power loss = V_{R1} x I_R (1 - D); I_R at V_{R1} = 80 % rated V_R



ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Current rating (5.5 A)

Package identifier:

W = D-PAK

4 - Schottky "Q" series

Voltage rating (06 = 60 V)

6 - FN = TO-252AA (D-PAK)

None = tube (50 pieces)

• TR = tape and reel

• TRL = tape and reel (left oriented)

• TRR = tape and reel (right oriented)

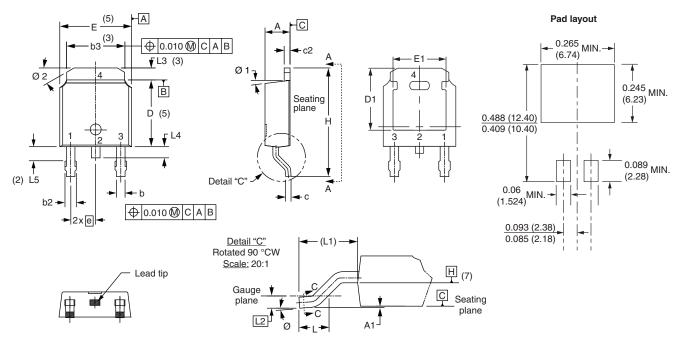
PbF = lead (Pb)-free

LINKS TO RELATED DOCUMENTS							
Dimensions	www.vishay.com/doc?95016						
Part marking information	www.vishay.com/doc?95059						
Packaging information	www.vishay.com/doc?95033						



D-PAK (TO-252AA)

DIMENSIONS in millimeters and inches



SYMBOL	MILLIN	IETERS	INC	HES	NOTES	NOTES	CVMPOL	MILLIMETERS		INCHES		NOTES
STIVIDUL	MIN.	MAX.	MIN.	MAX.	NOTES	NOTES	SYMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	2.18	2.39	0.086	0.094			е	2.29	BSC	0.090	BSC	
A1	-	0.13	-	0.005			Н	9.40	10.41	0.370	0.410	
b	0.64	0.89	0.025	0.035			L	1.40	1.78	0.055	0.070	
b2	0.76	1.14	0.030	0.045			L1	2.74	BSC	0.108	REF.	
b3	4.95	5.46	0.195	0.215	3		L2	0.51	BSC	0.020	BSC	
С	0.46	0.61	0.018	0.024			L3	0.89	1.27	0.035	0.050	3
c2	0.46	0.89	0.018	0.035			L4	-	1.02	-	0.040	
D	5.97	6.22	0.235	0.245	5		L5	1.14	1.52	0.045	0.060	2
D1	5.21	-	0.205	-	3		Ø	0°	10°	0°	10°	
Е	6.35	6.73	0.250	0.265	5		Ø1	0°	15°	0°	15°	
E1	4.32	-	0.170	-	3		Ø2	25°	35°	25°	35°	

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension uncontrolled in L5
- (3) Dimension D1, E1, L3 and b3 establish a minimum mounting surface for thermal pad
- (4) Section C C dimension apply to the flat section of the lead between 0.13 and 0.25 mm (0.005 and 0.10") from the lead tip
- (5) Dimension D, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (6) Dimension b1 and c1 applied to base metal only
- (7) Datum A and B to be determined at datum plane H
- (8) Outline conforms to JEDEC outline TO-252AA



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